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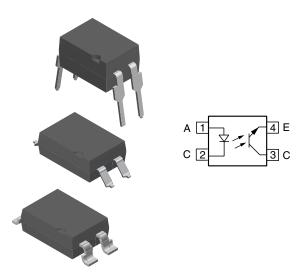








# Optocoupler, Phototransistor Output, High Reliability, 5300 V<sub>RMS</sub>



#### **DESCRIPTION**

The SFH610A and SFH6106 feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6 and option 8. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400  $V_{RMS}$  or DC. Specifications subject to change.

#### **FEATURES**

 Good CTR linearity depending on forward current



- Isolation test voltage, 5300 V<sub>RMS</sub>
- High collector emitter voltage, V<sub>CFO</sub> = 70 V
- Low saturation voltage
- · Fast switching times
- Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### AGENCY APPROVALS

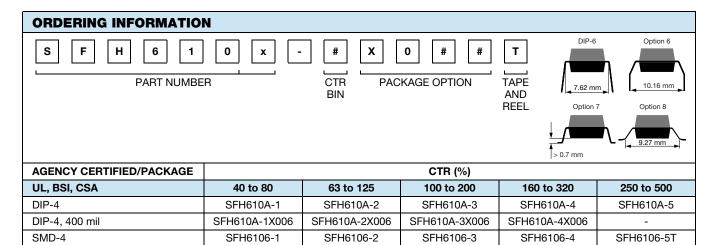
- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- CSA 93751
- BSI IEC 60950; IEC 60065

SFH610A-3X007

100 to 200

160 to 320

250 to 500



#### Note

SMD-4, option 7

VDE, UL, BSI, CSA (option 1)

SMD-4, 400 mil, option 8

• For additional information on the available options refer to option information.

40 to 80

SFH610A-1X018T

63 to 125



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		$V_R$	6	V			
DC forward current		I <sub>F</sub>	60	mA			
Surge forward current	t ≤ 10 μs	I <sub>FSM</sub>	2.5	А			
Power dissipation		P <sub>diss</sub>	100	mW			
OUTPUT							
Collector emitter voltage		$V_{CEO}$	70	V			
Emitter collector voltage		V <sub>ECO</sub>	7	V			
Collector current		I <sub>C</sub>	50	mA			
Collector current	t <sub>p</sub> ≤ 1.0 ms	I <sub>C</sub>	100	mA			
Power dissipation		P <sub>diss</sub>	150	mW			
COUPLER							
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C			
Ambient temperature range		T <sub>amb</sub>	-55 to +100	°C			
Soldering temperature (1)	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C			

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT										
Forward voltage	I <sub>F</sub> = 60 mA		$V_{F}$	-	1.25	1.65	V			
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>	-	0.01	10	μΑ			
Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz		Co	-	13	-	pF			
Thermal resistance			R <sub>thja</sub>	-	750	-	K/W			
OUTPUT										
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CE</sub>	-	5.2	-	pF			
Thermal resistance			R <sub>thja</sub>	-	500	-	K/W			
	V <sub>CE</sub> = 10 V	SFH610A-1	I <sub>CEO</sub>	-	2	50	nA			
		SFH6106-1	I <sub>CEO</sub>	-	2	50	nA			
		SFH610A-2	I <sub>CEO</sub>	-	2	50	nA			
		SFH6106-2	I <sub>CEO</sub>	-	2	50	nA			
Callegter emitter leakage current		SFH610A-3	I <sub>CEO</sub>	-	5	100	nA			
Collector emitter leakage current		SFH6106-3	I <sub>CEO</sub>	-	5	100	nA			
		SFH610A-4	I <sub>CEO</sub>	-	5	100	nA			
		SFH6106-4	I <sub>CEO</sub>	-	5	100	nA			
		SFH610A-5	I <sub>CEO</sub>	-	5	100	nA			
		SFH6106-5T	I <sub>CEO</sub>	-	5	100	nA			
COUPLER										
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V <sub>CEsat</sub>	-	0.25	0.4	V			
Coupling capacitance	f = 1 MHz		C <sub>C</sub>	-	0.4	-	pF			

#### Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		SFH610A-1	CTR	40	-	80	%	
		SFH6106-1	CTR	40	-	80	%	
		SFH610A-2	CTR	63	-	125	%	
		SFH6106-2	CTR	63	-	125	%	
	I = 10 m/s V = 5.0 V	SFH610A-3	CTR	100	-	200	%	
	$I_F = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}$	SFH6106-3	CTR	100	-	200	%	
		SFH610A-4	CTR	160	-	320	%	
		SFH6106-4	CTR	160	-	320	%	
1 //		SFH610A-5	CTR	250	-	500	%	
I <sub>C</sub> /I <sub>F</sub>		SFH6106-5	CTR	250	-	500	%	
		SFH610A-1	CTR	13	30	-	%	
		SFH6106-1	CTR	13	30	-	%	
		SFH610A-2	CTR	22	45	-	%	
$I_F = 1$ mA, $V_{CE} = 5$ V		SFH6106-2	CTR	22	45	-	%	
	IF = 1 IIIA, V <sub>CE</sub> = 5 V	SFH610A-3	CTR	34	70	=	%	
		SFH6106-3	CTR	34	70	-	%	
		SFH610A-4	CTR	56	90	=	%	
		SFH6106-4	CTR	56	90	=	%	

SWITCHING CHAR	ACTERISTICS						
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Current	$V_{CC} = 5 \text{ V}, R_{L} = 75 \Omega$		l <sub>F</sub>	-	10	-	mA
Rise time	$V_{CC} = 5 \text{ V}, R_{L} = 75 \Omega$		t <sub>r</sub>	-	2	-	μs
Fall time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>f</sub>	-	2	-	μs
Turn-on time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>on</sub>	-	3	-	μs
Turn-off time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>off</sub>	-	2.3	-	μs
Cut-off frequency	V <sub>CC</sub> = 5 V		F <sub>CO</sub>	-	250	-	kHz
SATURATED							
		SFH610A-1	I <sub>F</sub>	-	20	-	mA
		SFH6106-1					ША
		SFH610A-2	I <sub>F</sub>	-	10	-	mA
Current		SFH6106-2					ША
Current		SFH610A-3	l <sub>F</sub>	-	10	-	mA
		SFH6106-3					ША
		SFH610A-4		-	5	-	mA
		SFH6106-4	ı-	_			MA
SATURATED							
		SFH610A-1		ı	2	-	ш
		SFH6106-1	t <sub>r</sub>				μs
Rise time		SFH610A-2	+	-	3	-	ше
		SFH6106-2	t <sub>r</sub>				μs
		SFH610A-3	t <sub>r</sub>	-	3	-	ше
		SFH6106-3					μs
		SFH610A-4	+	-	4	-	μs
		SFH6106-4	t <sub>r</sub>		4		



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SWITCHING CHARACTERISTICS								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		SFH610A-1	t <sub>f</sub>		11	-		
		SFH6106-1		-	11		μs	
		SFH610A-2		-	14	-		
Fall time		SFH6106-2					μs	
raii liille		SFH610A-3	+.	_	14	_	ш	
		SFH6106-3	t <sub>f</sub>	_	14	-	μs	
		SFH610A-4	+	-	15	-		
		SFH6106-4	t <sub>f</sub>				μs	
		SFH610A-1	t <sub>on</sub>	-	3	-	ш	
		SFH6106-1					μs	
		SFH610A-2		-	4.2	-		
Turn-on time		SFH6106-2					μs	
rum-on time		SFH610A-3		-	4.2	-		
		SFH6106-3					μs	
		SFH610A-4		-	6	-	ш	
		SFH6106-4	t <sub>on</sub>				μs	
		SFH610A-1		-	18	-	ш	
		SFH6106-1	t <sub>off</sub>				μs	
Turn-off time		SFH610A-2	<b>+</b>	-	23	-	110	
		SFH6106-2	t <sub>off</sub>				μs	
		SFH610A-3		-	23	-	μs	
		SFH6106-3						
		SFH610A-4	+	_	25	-	II.E	
		SFH6106-4	t <sub>off</sub>	-			μs	

#### Note

• All values presented are typical values.

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V <sub>ISO</sub>	4420	V <sub>RMS</sub>
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V <sub>IOTM</sub>	10 000	V
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V <sub>IORM</sub>	890	V
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Output safety power		P <sub>SO</sub>	400	mW
Input safety current		I <sub>SI</sub>	275	mA
Input safety temperature		T <sub>SI</sub>	175	°C
Creepage distance	DID 4 / SMD 4		≥ 7	mm
Clearance distance	DIP-4 / SMD-4		≥ 7	mm
Creepage distance	DID 4 400 mil / SMD 4 400 mil		≥ 8	mm
Clearance distance	DIP-4, 400 mil / SMD-4, 400 mil		≥ 8	mm
Insulation thickness		DTI	≥ 0.4	mm

#### Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

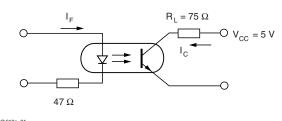


Fig. 1 - Linear Operation (without saturation)

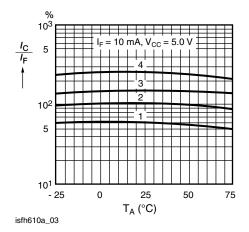


Fig. 2 - Current Transfer Ratio (CTR) vs. Temperature

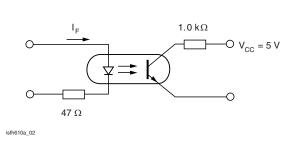


Fig. 3 - Switching Operation (with saturation)

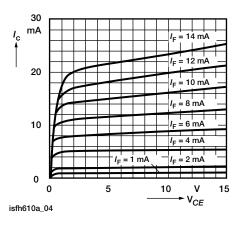


Fig. 4 - Output Characteristics (typ.) Collector Current vs. Collector Emitter Voltage

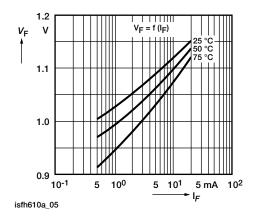


Fig. 5 - Diode Forward Voltage vs. Forward Current

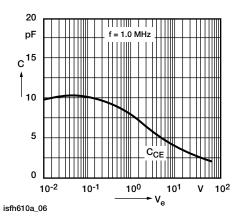


Fig. 6 - Transistor Capacitance (typ.) vs. Collector Emitter Voltage



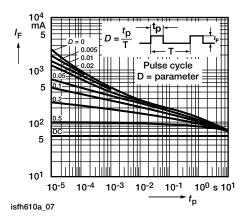


Fig. 7 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

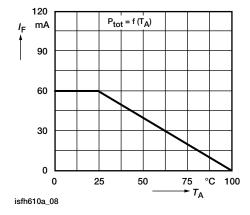


Fig. 8 - Permissible Power Dissipation vs. Temperature

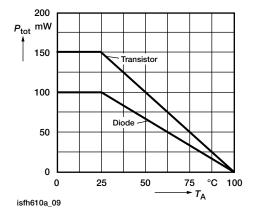
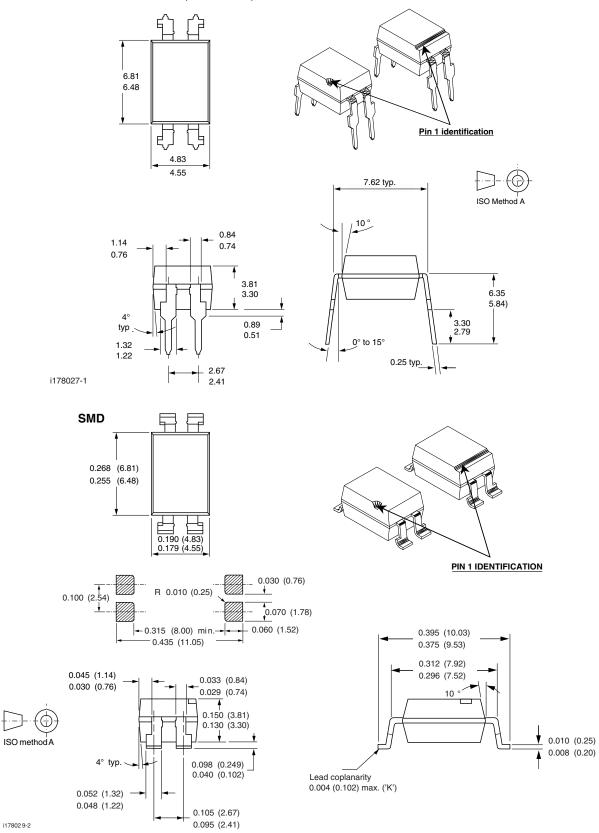


Fig. 9 - Permissible Diode Forward Current vs. Ambient Temperature

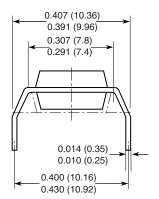
### **PACKAGE DIMENSIONS** in inches (millimeters)



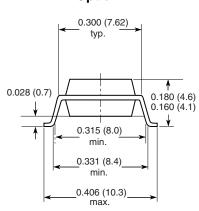




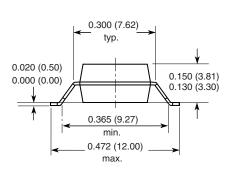
### Option 6



### Option 7



### **Option 8**





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